# **Ultra High Accuracy,** Low Iq, 500 mA **Low Dropout Regulator**

The NCP3335 is a high performance, low dropout regulator. With accuracy of ±0.9% over line and load and ultra-low quiescent current and noise it encompasses all of the necessary features required by today's consumer electronics. This unique device is guaranteed to be stable without a minimum load current requirement and stable with any type of capacitor as small as 1.0 μF. The NCP3335 also comes equipped with sense and noise reduction pins to increase the overall utility of the device.

#### **Features**

- High Accuracy Over Line and Load (±0.9% at 25°C)
- Ultra-Low Dropout Voltage at Full Load (260 mV typ.)
- No Minimum Output Current Required for Stability
- Low Noise (35  $\mu$ Vrms w/ 10 nF  $C_{nr}$  and 56  $\mu$ Vrms w/out  $C_{nr}$ )
- Low Shutdown Current (0.07 µA)
- 2.6 V to 12 V Supply Range
- Thermal Shutdown Protection
- Current Limitation
- ard
  Catular Phones

  Camcoders and Cameras

  Networking Systems, DSL/Cable Modems

  Cable Set-Top Box

  MP3/CD Players
  DSP Supply
  Displays and Monitors



#### ON Semiconductor®

http://onsemi.com



Micro8™ **DMR2 SUFFIX CASE 846A** 



QFN10 MN SUFFIX **CASE 485C** 

#### MARKING DIAGRAM



1,2. V<sub>out</sub> 3. Sense

4. GND 5. NR

6. SD (Shutdown)

7,8. V<sub>in</sub>

3335 ALYW=

XXX

Pin 1,2. Vout

3. Sense 4. GND

5,6. NC 7. NR

8. SD 9,10. V<sub>in</sub>

= LHX for 2.5 V = LHY for 2.85 V

= LHZ for 3.3 V

= Assembly Location

= Wafer Lot Υ = Year

W = Work Week

= Pb-Free Package (Note: Microdot may be in either location)

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

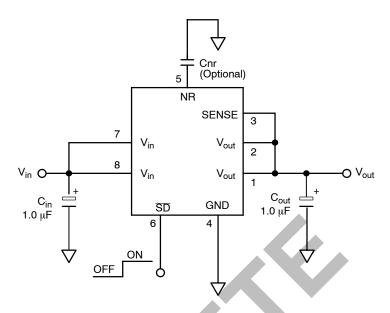


Figure 1. Typical Application Schematic (Micro8 Package)

#### PIN FUNCTION DESCRIPTION

			OFF A
			0,1
		Figure	1. Typical Application Schematic (Micro8 Package)
			A COUCH AS
PIN FUNC	TION DESC	CRIPTION	
Pin No. Micro8	Pin No. QFN10	Pin Name	Description
1, 2	1, 2	V <sub>out</sub>	Regulated output voltage. Bypass to ground with $C_{out} \ge 1.0  \mu F$ .
3	3	SENSE	For output voltage sensing, connect to Pins 1 and 2.
4	4	GND	Power Supply Ground
5	7	NR	Noise Reduction Pin. This is an optional pin used to further reduce noise.
6	8	SD	Shutdown pin. When not in use, this pin should be connected to the input pin.
7, 8	9, 10	V <sub>in</sub>	Power Supply Input Voltage
-	5, 6	NC	Not Connected

# **ABSOLUTE MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Input Voltage	V <sub>in</sub>	-0.3 to +16	V
Output Voltage	V <sub>out</sub>	-0.3 to V <sub>in</sub> +0.3	V
Shutdown Pin Voltage	$V_{\sf sh}$	-0.3 to +16	V
Thermal Characteristics Thermal Resistance, Junction-to-Air	$R_{ hetaJA}$	238	°C/W
Operating Junction Temperature Range	TJ	-40 to +150	°C
Storage Temperature Range	T <sub>stg</sub>	-50 to+150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

This device series contains ESD protection and exceeds the following tests:

Human Body Model (HBM) JESD 22-A114-B Machine Model (MM) JESD 22-A115-A

# $\textbf{ELECTRICAL CHARACTERISTICS - 2.5 V} \ (V_{out} = 2.5 \ V \ typical, \ V_{in} = 2.9 \ V, \ T_{A} = -40 ^{\circ}\text{C} \ to \ +85 ^{\circ}\text{C}, \ unless \ otherwise \ noted)$

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (Accuracy) $V_{in} = 2.9 \text{ V to } 6.5 \text{ V, I}_{load} = 0.1 \text{ mA to } 500 \text{ mA, T}_J = 25^{\circ}\text{C}$	V <sub>out</sub>	-0.9% 2.477	2.5	+0.9% 2.523	V
Output Voltage (Accuracy) $V_{in} = 2.9 \text{ V to } 6.5 \text{ V, I}_{load} = 0.1 \text{ mA to } 500 \text{ mA, T}_J = 0^{\circ}\text{C to } +85^{\circ}\text{C}$	V <sub>out</sub>	-1.4% 2.465	2.5	+1.4% 2.535	٧
Output Voltage (Accuracy), (Note 1) $V_{in} = 2.9 \text{ V to } 6.5 \text{ V}, I_{load} = 0.1 \text{ mA to } 500 \text{ mA}, T_J = -40^{\circ}\text{C to } +150^{\circ}\text{C}$	V <sub>out</sub>	-1.5% 2.462	2.5	+1.5% 2.538	V
Line Regulation $V_{in} = 2.9 \text{ V to } 6.5 \text{ V}, I_{load} = 0.1 \text{ mA}$	Line <sub>Reg</sub>		0.04		mV/V
Load Regulation V <sub>in</sub> = 2.9 V, I <sub>load</sub> = 0.1 mA to 500 mA	Load <sub>Reg</sub>		0.04		mV/mA
Dropout voltage    I <sub>load</sub> = 500 mA (Note 2)     I <sub>load</sub> = 300 mA (Note 2)     I <sub>load</sub> = 50 mA     I <sub>load</sub> = 0.1mA	V <sub>DO</sub>			340 230 110	mV
Peak Output Current (See Figure 6)	I <sub>pk</sub>	500	700	800	mA
Short Output Current (See Figure 6)	I <sub>sc</sub>		.()	900	mA
Thermal Shutdown	TJ		160		°C
Ground Current In Regulation Iload = 500 mA (Note 2) Iload = 300 mA (Note 2) Iload = 50 mA Iload = 50 mA Iload = 0.1 mA  In Dropout Vin = 2.4 V, Iload = 0.1 mA	I <sub>GND</sub>	CRI	9.0 4.6 0.8 -	14 7.5 2.5 190	mA μA μA
In Shutdown S <sub>D</sub> = 0 V	IGNDsh		0.07	1.0	μΑ
Output Noise $\begin{array}{l} C_{nr}=0 \text{ nF, } I_{load}=500 \text{ mA, } f=10 \text{ Hz to } 100 \text{ kHz, } C_{out} \neq 10  \mu\text{F} \\ C_{nr}=10 \text{ nF, } I_{load}=500 \text{ mA, } f=10 \text{ Hz to } 100 \text{ kHz, } C_{out} = 10  \mu\text{F} \end{array}$	V <sub>noise</sub>		56 35		μVrms μVrms
Shutdown Threshold Voltage ON Threshold Voltage OFF		2.0		0.4	V V
$\overline{SD}$ Input Current, $V_{SD}$ = 0 V to 0.4 V or $V_{SD}$ = 2.0 V to $V_{in}$	I <sub>SD</sub>		0.07	1.0	μΑ
Output Current In Shutdown Mode, Vout = 0 V	I <sub>OSD</sub>		0.07	1.0	μΑ

For proper operation below T<sub>J</sub> = 0°C, please refer to Figure 8.
 T<sub>A</sub> must be greater than 0°C.

# $\textbf{ELECTRICAL CHARACTERISTICS - 2.85 V} \ (V_{out} = 2.85 \ V \ typical, \ V_{in} = 3.25 \ V, \ T_{A} = -40 ^{\circ}C \ to \ +85 ^{\circ}C, \ unless \ otherwise \ noted)$

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (Accuracy) $V_{in} = 3.25 \text{ V}$ to 6.85 V, $I_{load} = 0.1 \text{ mA}$ to 500 mA, $T_J = 25^{\circ}\text{C}$	V <sub>out</sub>	-0.9% 2.824	2.85	+0.9% 2.876	V
Output Voltage (Accuracy) $V_{in} = 3.25$ V to 6.85 V, $I_{load} = 0.1$ mA to 500 mA, $T_{J} = 0$ °C to +85°C	V <sub>out</sub>	-1.4% 2.810	2.85	+1.4% 2.890	V
Output Voltage (Accuracy) (Note 3) $V_{in}=3.25$ V to 6.85 V, $I_{load}=0.1$ mA to 500 mA, $T_{J}=-40^{\circ}\text{C}$ to +150°C	V <sub>out</sub>	-1.5% 2.807	2.85	+1.5% 2.893	V
Line Regulation V <sub>in</sub> = 3.25 V to 6.85 V, I <sub>load</sub> = 0.1 mA	Line <sub>Reg</sub>		0.04		mV/V
Load Regulation V <sub>in</sub> = 3.25 V, I <sub>load</sub> = 0.1 mA to 500 mA	Load <sub>Reg</sub>		0.04		mV/mA
Dropout voltage   I <sub>load</sub> = 500 mA     I <sub>load</sub> = 300 mA     I <sub>load</sub> = 50 mA     I <sub>load</sub> = 0.1mA	V <sub>DO</sub>			340 230 110	mV
Peak Output Current (See Figure 6)	I <sub>pk</sub>	500	700	800	mA
Short Output Current (See Figure 6)	I <sub>sc</sub>		.()	900	mA
Thermal Shutdown	TJ		160		°C
Ground Current In Regulation I <sub>load</sub> = 500 mA (Note 4) I <sub>load</sub> = 300 mA I <sub>load</sub> = 50 mA I <sub>load</sub> = 0.1 mA In Dropout	I <sub>GND</sub>	CRI	9.0 4.6 0.8 -	14 7.5 2.5 190	mA μA
V <sub>in</sub> = 2.75 V, I <sub>load</sub> = 0.1 mA In Shutdown SD = 0 V	IGNDsh	K	0.07	500 1.0	μΑ μΑ
Output Noise $C_{nr} = 0$ nF, $I_{load} = 500$ mA, $f = 10$ Hz to 100 kHz, $C_{out} = 10$ $\mu$ F $C_{nr} = 10$ nF, $I_{load} = 500$ mA, $f = 10$ Hz to 100 kHz, $C_{out} = 10$ $\mu$ F	V <sub>noise</sub>		61 40		μVrms μVrms
Shutdown Threshold Voltage ON Threshold Voltage OFF		2.0		0.4	V
$S_D$ Input Current, $V_{SD}$ = 0 V to 0.4 V or $V_{SD}$ = 2.0 V to $V_{in}$	I <sub>SD</sub>		0.07	1.0	μΑ
Output Current In Shutdown Mode, Vout = 0 V	I <sub>OSD</sub>		0.07	1.0	μΑ

<sup>3.</sup> For proper operation below T<sub>J</sub> = 0°C, please refer to Figure 7.
4. T<sub>A</sub> must be greater than 0°C.

# $\textbf{ELECTRICAL CHARACTERISTICS - 3.3 V} \ (V_{out} = 3.3 \ V \ typical, \ V_{in} = 3.7 \ V, \ T_{A} = -40 ^{\circ}\text{C to } +85 ^{\circ}\text{C}, \ unless \ otherwise \ noted)$

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (Accuracy) $V_{in} = 3.7 \text{ V to } 7.3 \text{ V, I}_{load} = 0.1 \text{ mA to } 500 \text{ mA, T}_J = 25^{\circ}\text{C}$	V <sub>out</sub>	-0.9% 3.270	3.3	+0.9% 3.330	V
Output Voltage (Accuracy) $V_{in}=3.7$ V to 7.3 V, $I_{load}=0.1$ mA to 500 mA, $T_J=0^{\circ}C$ to $+85^{\circ}C$	V <sub>out</sub>	-1.4% 3.254	3.3	+1.4% 3.346	V
Output Voltage (Accuracy) $V_{in} = 3.7$ V to 7.3 V, $I_{load} = 0.1$ mA to 500 mA, $T_{J} = -40^{\circ}$ C to +150°C	V <sub>out</sub>	-1.5% 3.250	3.3	+1.5% 3.350	V
Line Regulation $V_{in} = 3.7 \text{ V to } 7.3 \text{ V, } I_{load} = 0.1 \text{ mA}$	Line <sub>Reg</sub>		0.04		mV/V
Load Regulation $V_{in} = 3.7 \text{ V}, I_{load} = 0.1 \text{ mA to } 500 \text{ mA}$	Load <sub>Reg</sub>		0.04		mV/mA
Dropout Voltage  I <sub>load</sub> = 500 mA  I <sub>load</sub> = 300 mA  I <sub>load</sub> = 50 mA  I <sub>load</sub> = 50 mA	V <sub>DO</sub>			340 230 110	mV
Peak Output Current (See Figure 6)	lpk	500	700	800	mA
Short Output Current (See Figure 6)	I <sub>sc</sub>		.(3)	900	mA
Thermal Shutdown	TJ		160		°C
Ground Current In Regulation I <sub>load</sub> = 500 mA (Note 5) I <sub>load</sub> = 300 mA I <sub>load</sub> = 50 mA I <sub>load</sub> = 0.1 mA In Dropout	I <sub>GND</sub>	ICON ICON	9.0 4.6 0.8 -	14 7.5 2.5 190	mA μA
$V_{in}$ = 3.2 V, $I_{load}$ = 0.1 mA In Shutdown $S_D$ = 0 V	IGNDsh		0.07	500 1.0	μΑ μΑ
Output Noise $C_{nr}=0 \text{ nF, } I_{load}=500 \text{ mA, } f=10 \text{ Hz to } 100 \text{ kHz, } C_{out}=10  \mu\text{F}$ $C_{nr}=10 \text{ nF, } I_{load}=500 \text{ mA, } f=10 \text{ Hz to } 100 \text{ kHz, } C_{out}=10  \mu\text{F}$	V <sub>noise</sub>		69 46		μVrms μVrms
Shutdown Threshold Voltage ON Threshold Voltage OFF		2.0		0.4	V V
$S_D$ Input Current, $V_{SD} = 0$ V to 0.4 V or $V_{SD} = 2.0$ V to $V_{in}$	I <sub>SD</sub>		0.07	1.0	μΑ
Output Current In Shutdown Mode, V <sub>out</sub> = 0 V	I <sub>OSD</sub>		0.07	1.0	μΑ

<sup>5.</sup> T<sub>A</sub> must be greater than 0°C.

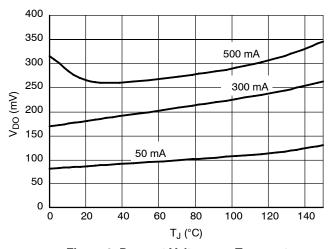


Figure 2. Dropout Voltage vs. Temperature

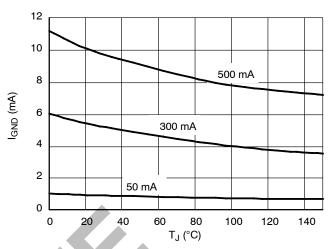


Figure 3. Ground Current vs. Temperature

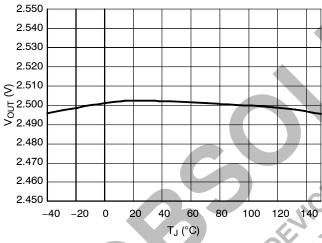


Figure 4. Output Voltage vs. Temperature

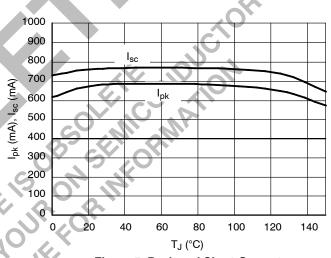


Figure 5. Peak and Short Current vs. Temperature

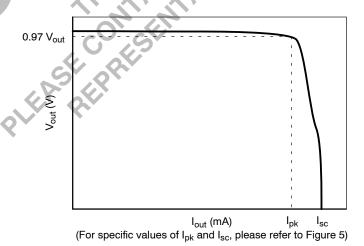


Figure 6. Output Voltage vs. Output Current

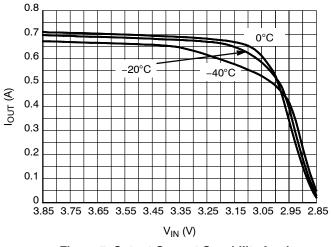


Figure 7. Output Current Capability for the 2.85 V Version

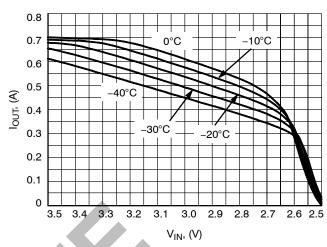
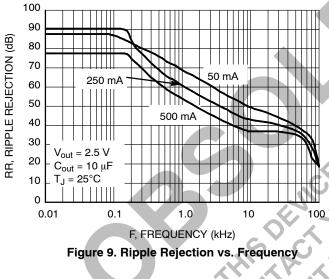


Figure 8. Output Current Capability for the 2.5 V Version



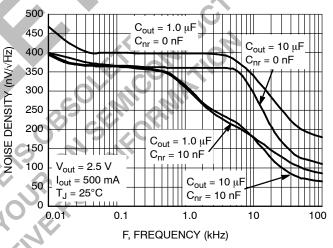


Figure 10. Output Noise Density

#### **ORDERING INFORMATION**

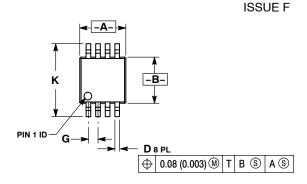
Device	Nominal Output Voltage	Package	Shipping $^{\dagger}$
NCP3335DMR2250G	2.5 V	Micro8 (Pb-Free)	4000 / Tape & Reel
NCP3335DMR2285G	2.85 V	Micro8 (Pb-Free)	4000 / Tape & Reel
NCP3335DMR2330G	3.3 V	Micro8 (Pb-Free)	4000 / Tape & Reel
NCP3335MN250R2G	2.5 V	QFN10 (Pb-Free)	4000 / Tape & Reel
NCP3335MN330R2G	3.3 V	QFN10 (Pb-Free)	4000 / Tape & Reel

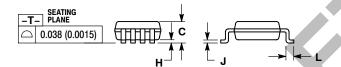
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>Please contact factory for other voltage options.

#### PACKAGE DIMENSIONS

#### Micro8 CASE 846A-02





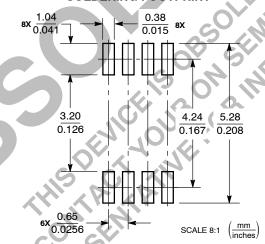
#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- 7/14.5M, 1982.
  CONTROLLING DIMENSION: MILLIMETER.
  DIMENSION A DOES NOT INCLUDE MOLD FLASH,
  PROTRUSIONS OR GATE BURRS. MOLD FLASH,
- PHOT HUSIONS OF GATE BURRS. MIOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

  DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PED SIDE.
- 846A-01 OBSOLETE, NEW STANDARD 846A-02.

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	2.90	3.10	0.114	0.122	
В	2.90	3.10	0.114	0.122	
Ç		1.10		0.043	
D	0.25	0.40	0.010	0.016	
G	0.65	BSC	0.026	BSC	
Н	0.05	0.15	0.002	0.006	
J	0.13	0.23	0.005	0.009	
K	4.75	5.05	0.187	0.199	
L	0.40	0.70	0.016	0.028	

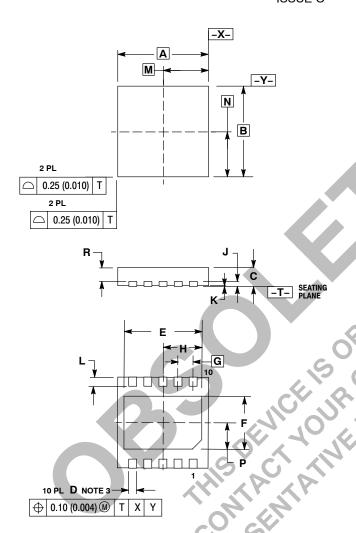
# **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

#### 10 Pin QFN CASE 8485C-01 ISSUE O



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION D APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM FROM TERMINAL.
- 4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	MILLIN	IETERS	ERS INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	3.00	BSC	0.118	BSC	
В	3.00	BSC	0.118	BSC	
С	0.80	1.00	0.031	0.039	
D	0.20	0.30	0.008	0.012	
E	2.45	2.55	0.096	0.100	
F	1.75	1.85	0.069	0.073	
G	0.50	BSC	0.020 BSC		
Н	1.23	1.28	0.048	0.050	
J	0.20	REF	0.008	REF	
K	0.00	0.05	0.000	0.002	
<u>- 6</u>	0.35	0.45	0.014	0.018	
M	1.50 BSC		0.059 BSC		
N	1.50 BSC		0.059	BSC	
P	0.88	0.93	0.035	0.037	
R	0.60	0.80	0.024	0.031	

The products described herein NCP3335, may be covered by one or more of the following U.S. patents; 5,920,184, 5,966,004, and 5,834,926. There may be other patents pending.

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NCP3335/D